# NSN 5961-00-851-8293

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.240 inches and 0.390 inches

## **Overall Diameter:**

Between 0.335 inches and 0.370 inches

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Terminal

## Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 20.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

70.00 microamperes zero-gate-voltage source current preset and 500.00 milliamperes source cutoff current blank

## **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector

## **Special Features:**

Junction pattern arrangement: pnp

## Terminal Type And Quantity:

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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